

ULTRA LOW CAPACITANCE TVS DIODE ARRAY

Features

- Ultra low capacitance: 0.3pF typical (I/O to I/O)
- Ultra low leakage: nA level
- Operating voltage: 5V
- Low clamping voltage
- Up to four lines protects
- Leadless flow-through package
- Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test
 - Air discharge: $\pm 15\text{kV}$
 - Contact discharge: $\pm 8\text{kV}$
 - IEC61000-4-5 (Lightning) 4A (8/20 μs)
- RoHS Compliant

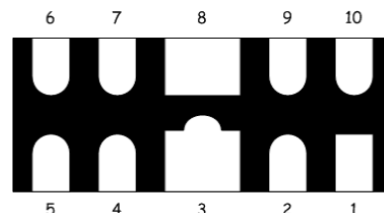
Applications

- HDMI 1.3 & 1.4, USB 2.0 & 3.0 and MDDI ports
- Monitors and flat panel displays
- Set-top box and Digital TV
- Video graphics cards
- Digital Visual Interface (DVI)
- Notebook Computers
- PCI Express and Serial SATA Ports

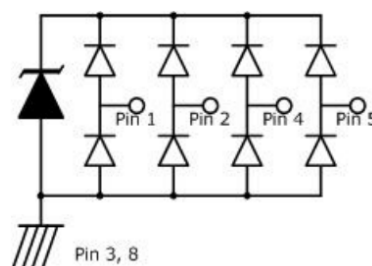
Mechanical Characteristics

- Package: DFN2510-10 (2.5 $\times$ 1.0 $\times$ 0.5mm)
- Lead Finish: Matte Tin
- Case Material: "Green" Molding Compound.
- Moisture Sensitivity: Level 3 per J-STD-020
- Terminal Connections: See Diagram Below
- Marking Information: See Below

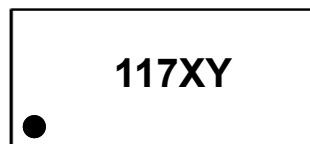
Dimensions DFN2510P10



Pin Configuration



Marking Information



117= Device Marking Code
XY= Date Code
Dot denotes Pin1

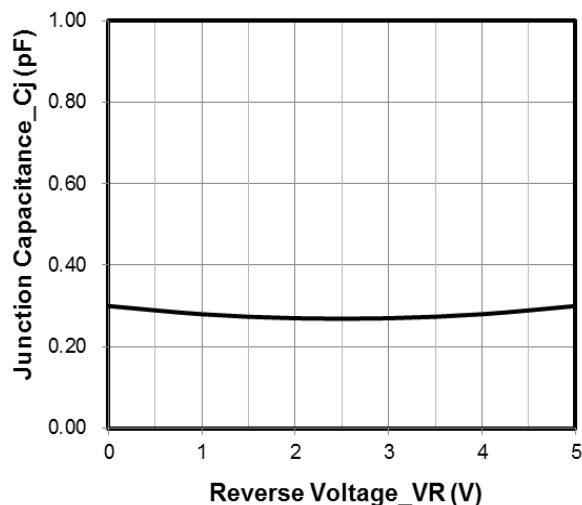
Absolute Maximum Ratings (Tamb=25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20 μs)	Ppp	40	W
ESD per IEC 61000-4-2 (Air)	V _{ESD}	± 15	Kv
ESD per IEC 61000-4-2 (Contact)		± 8	
Operating Temperature Range	T _J	-55 to +125	°C
Storage Temperature Range	T _{STJ}	-55 to +150	°C

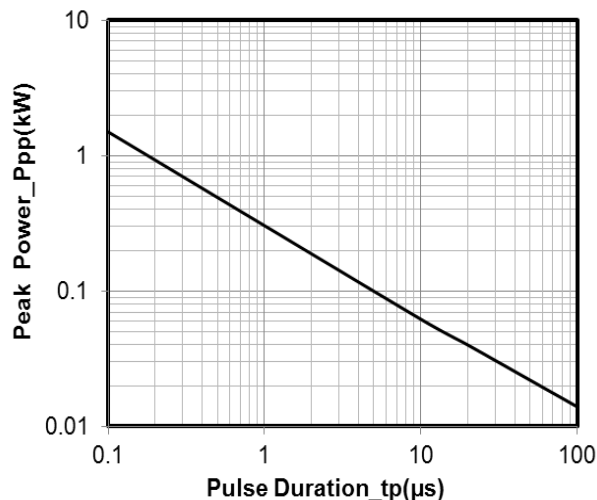
Electrical Characteristics (T_A=25°C unless otherwise specified)

Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	V _{RWM}			5	V	Any I/O pin to ground
Breakdown Voltage	V _{BR}	5.8			V	I _T = 2μA, any I/O pin to ground
Breakdown Voltage	V _{BR}		8		V	I _T = 1mA, any I/O pin to ground
Reverse Leakage Current	I _R			0.5	μA	V _{RWM} = 5V, any I/O pin to ground
Clamping Voltage	V _C			9	V	I _{PP} = 1A (8 x 20μs pulse), any I/O pin to ground
Clamping Voltage	V _C			10	V	I _{PP} = 4A (8 x 20μs pulse), any I/O pin to ground
Junction Capacitance	C _J		0.3	0.4	pF	V _R = 0V, f = 1MHz, between I/O pins
Junction Capacitance	C _J		0.6	0.8	pF	V _R = 0V, f = 1MHz, any I/O pin to ground

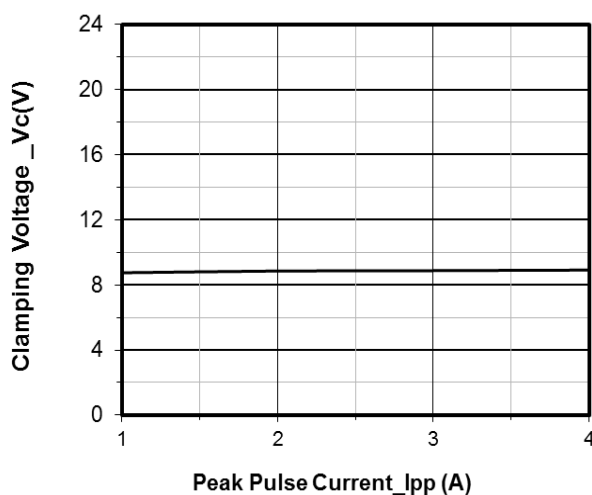
Typical Performance Characteristics ($T_A=25^\circ\text{C}$ unless otherwise Specified)



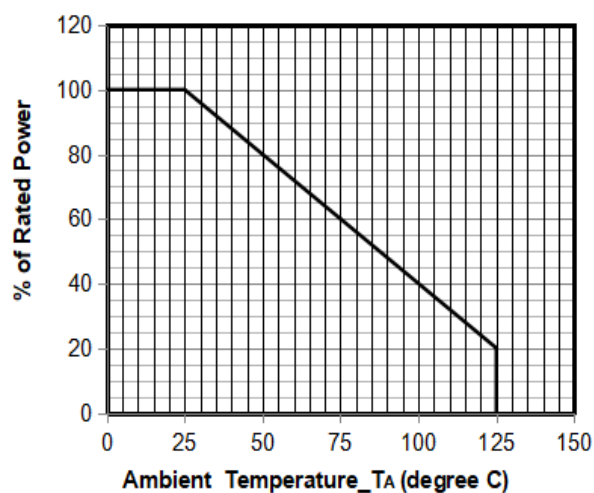
Junction Capacitance vs. Reverse Voltage



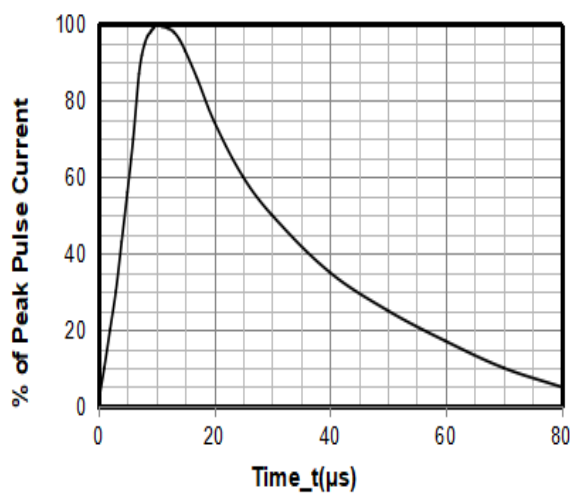
Peak Pulse Power vs. Pulse Time



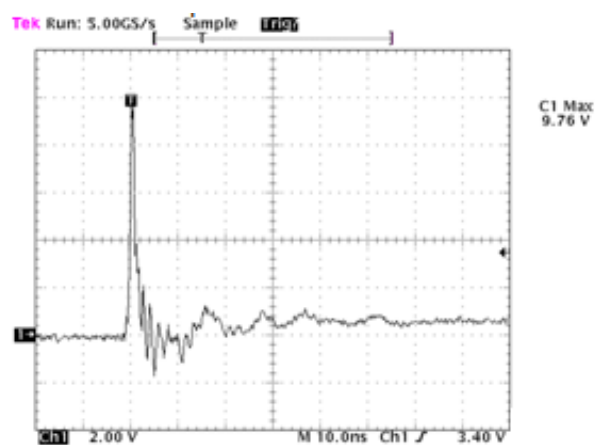
Clamping Voltage vs. Peak Pulse Current



Power Derating Curve



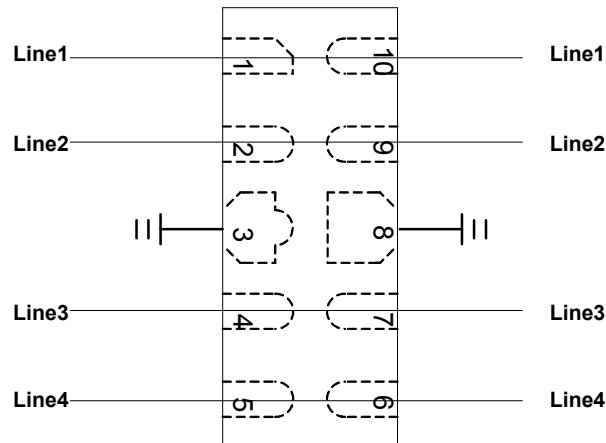
8 X 20 μs Pulse Waveform



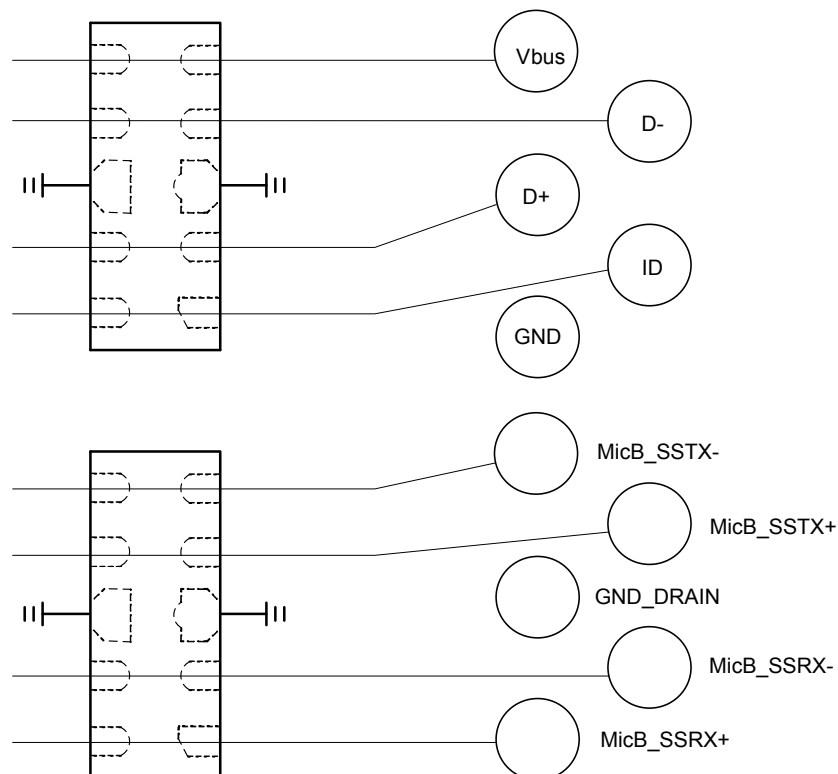
Note: Data is taken with a 10x attenuator
Contact discharge current waveform
per IEC61000-4-2

Typical Application

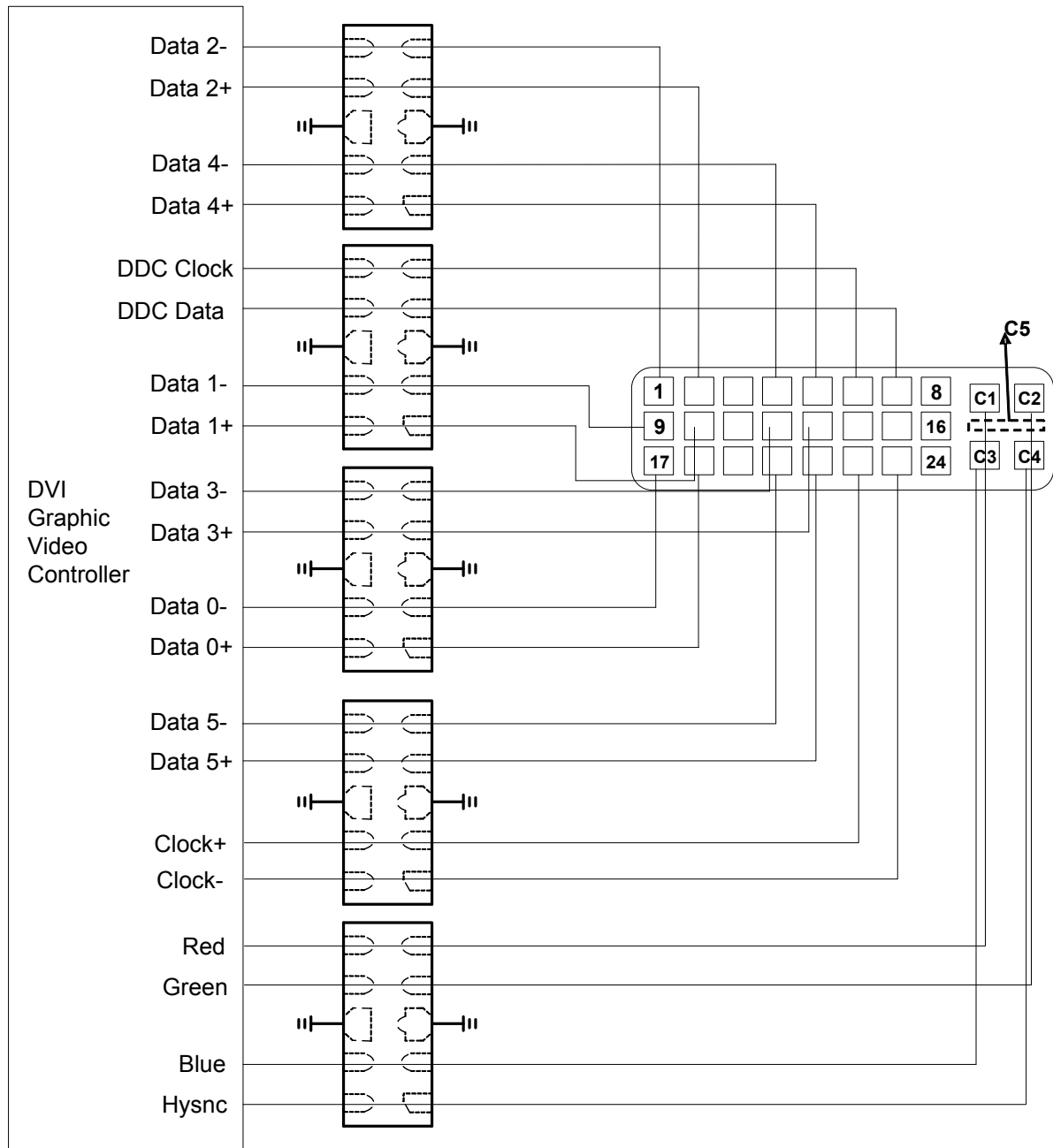
The ULC0544P10 is designed for easy PCB layout by allowing the traces to run straight through the device. The PCB traces could be used to connect the pin pairs for each line. For example, line 1 enters at pin 1 and exits at pin 10 and the PCB trace connects Pin 1 and Pin 10 together. Ground is connected at Pin 3 and Pin 8.



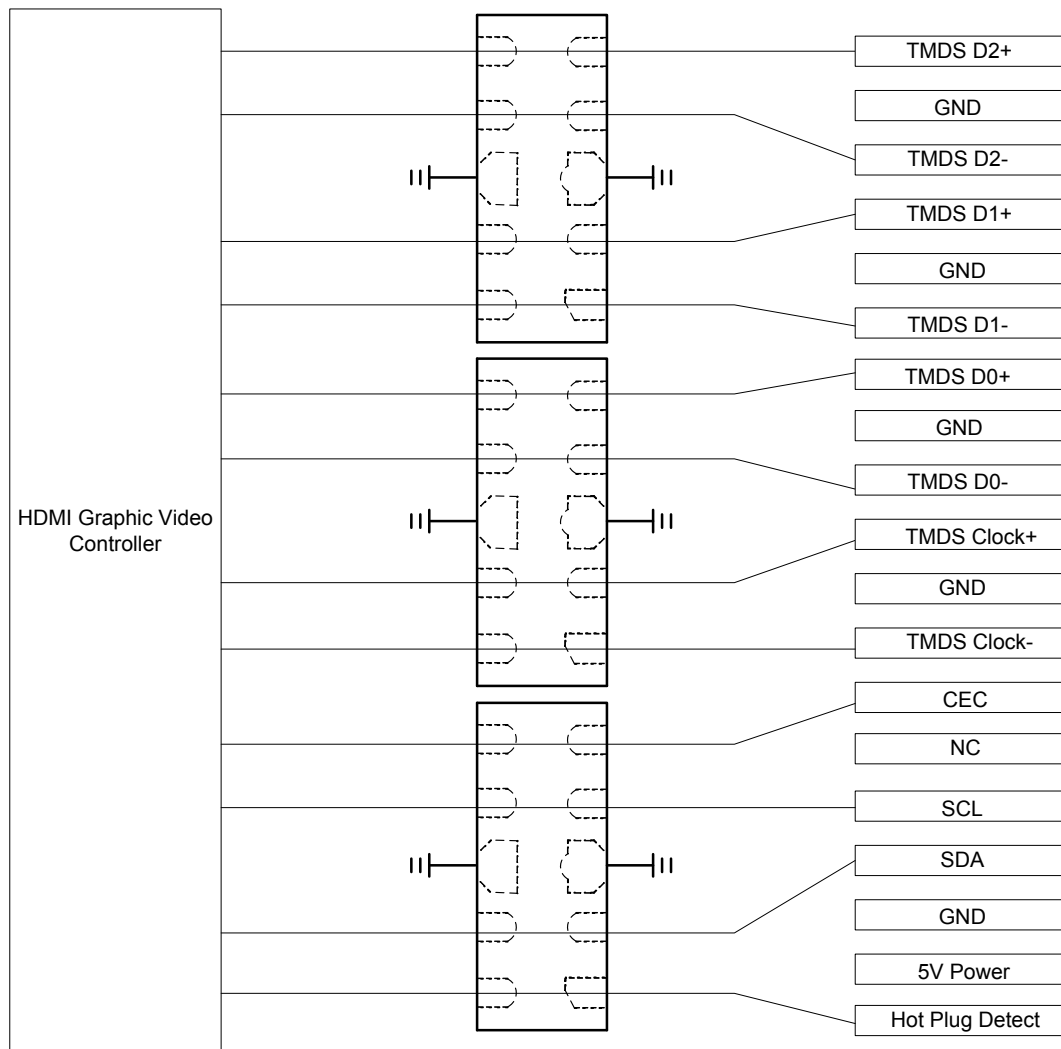
ULC0544P10 on USB 3.0 Port Application



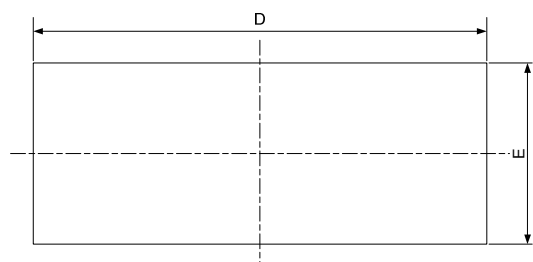
ULC0544P10on DVI Port Application



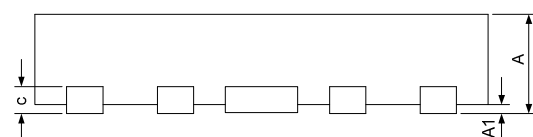
ULC0544P10on HDMI Port Application



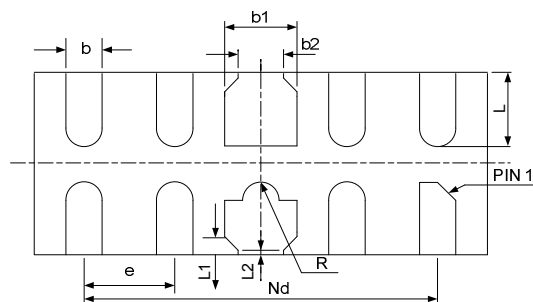
DFN2510-10 Package Outline Drawing



TOP VIEW



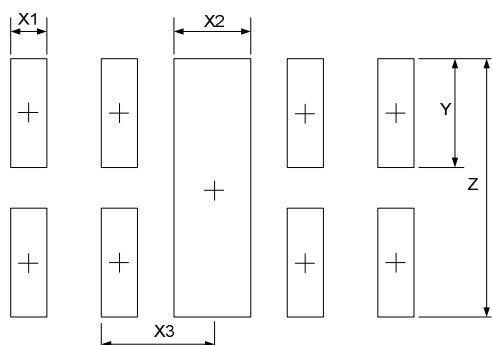
SIDE VIEW



BOTTOM VIEW

SYM	DIMENSIONS					
	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.45	0.50	0.55	0.018	0.020	0.022
A1	0.00	0.02	0.05	0.000	0.001	0.002
b	0.15	0.20	0.25	0.006	0.008	0.010
b1	0.35	0.40	0.45	0.014	0.016	0.018
b2	0.20	0.25	0.30	0.008	0.010	0.012
c	0.10	0.15	0.20	0.004	0.006	0.008
D	2.45	2.50	2.55	0.098	0.100	0.102
e	0.50BSC			0.020BSC		
Nd	2.00BSC			0.080BSC		
E	0.95	1.00	1.05	0.038	0.040	0.042
L	0.35	0.40	0.45	0.014	0.016	0.018
L1	0.075REF			0.003REF		
L2	0.050REF			0.002REF		
h	0.08	0.12	0.15	0.003	0.005	0.006
R	0.05	0.10	0.15	0.002	0.004	0.006

Suggested Land Pattern



SYM	DIMENSIONS	
	MILLIMETERS	INCHES
X1	0.200	0.008
X2	0.400	0.016
X3	0.500	0.020
Y	0.600	0.024
Z	1.400	0.056